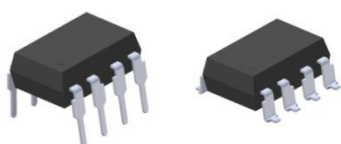
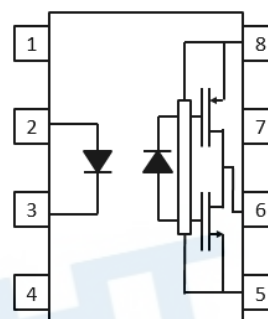


8PIN DIP IGBT/MOSFET 1A Output Current GATE DRIVER PHOTOCOUPLER EL3150 Series



Schematic



Pin Configuration

- 1, No Connection
- 2, Anode
- 3, Cathode
- 4, No Connection
- 5, V_{EE}
- 6, V_{OUT}
- 7, No Connection
- 8, V_{CC}

A 0.1 μ F bypass capacitor must be connected between pins 8 and 5

Features:

- Rail-to-rail output swing
- Guaranteed performance from -40 to 110°C
- Peak Output Current : $I_{OP} = 1A$ (max)
- Threshold Input Current: $I_{FLH} = 5$ mA (max)
- High isolation voltage between input and output (Viso=5000 V rms)
- Pb free and RoHS compliant.
- UL and cUL approved
- VDE approved
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

Description

The EL3150 consists of an infrared light emitting diodes and integrated high gain, high-speed photo detectors. The device is housed in a 8 pin DIP package.

The photo detector has an internal shield that provides guaranteed common-mode transient immunity of ± 25 kV/ μ s. It is suitable for direct gate driving circuit for IGBTs or power MOSFETs.

Applications

- Isolated IGBT/Power MOSFET Gate Drive
- Uninterruptible power supply
- Inverters
- Home appliances, such as fan heaters, etc.

Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	25	mA
	Pulse Forward Current* ¹	I _{FP}	1	A
	Reverse voltage	V _R	5	V
Output	"H" Peak Output current	I _{OPH}	1	A
	"L" Peak Output Current	I _{OPL}	1	A
	Pear Output Voltage	V _O	30	V
	Supply Voltage	V _{CC} -V _{EE}	15 to 30	V
	Operating frequency	f	50	kHz
	Isolation voltage * ²	V _{ISO}	5000	V rms
	Total Power Dissipation	P _T	300	mW
	Operating temperature	T _{OPR}	-40 ~ +110	°C
	Storage temperature	T _{STG}	-55 ~ +125	°C
	Soldering temperature * ³	T _{SOL}	260	°C

Notes:

*1 Pulse width ≤ 1μs, 300pps.

*2 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 to 4 are shorted together, and pins 5 to 8 are shorted together.

*3 For 10 seconds.

Electro-Optical Characteristics (T_A=-40~110°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage	V _F	-	-	1.8	V	I _F = 10mA
Reverse Current	V _R	5	-	-	V	I _R = 10μA

Output

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
High level supply current	I _{CCH}	-	1.6	3.2	mA	I _F =10mA, V _{CC} =30V V _O = Open
Low level supply current	I _{CCL}	-	2.0	3.2		I _F =0mA, V _{CC} =30V V _O = Open

Transfer Characteristics

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
High Level Output Current*4	I _{OH}	-	-1	-0.2	A	I _F =10mA, V _{CC} =30V, V _O =V _{CC} -1V
		-	-	-1		I _F =10mA, V _{CC} =30V, V _O =V _{CC} -4V
Low Level Output Current*4	I _{OL}	0.2	1	-		I _F =0mA, V _{CC} =30V, V _O =V _{EE} +1V
		1	-	-		I _F =0mA, V _{CC} =30V, V _O =V _{EE} +4V
High Level Output Voltage	V _{OH}	V _{CC} -4	-	-	V	I _F =10mA, V _{CC} =30V, I _O =-1A
		V _{CC} -0.5	-	-	V	I _F =10mA, V _{CC} =30V, I _O =-100mA
Low Level Output Voltage	V _{OL}	-	-	V _{EE} +4	V	I _F =10mA, V _{CC} =30V, I _O =1A
		-	-	V _{EE} +0.5	V	I _F =10mA, V _{CC} =30V, I _O =100mA
Input Threshold Current	I _{FLH}	-	1.5	5	mA	V _{CC} =15 or 30V, V _O >5V
Input Threshold Voltage	V _{FHL}	0.8	-	-	V	V _{CC} =15 or 30V, V _O <5V
Under Voltage Lockout Threshold	V _{UVLO+}	11.0	-	13.5	V	I _F =10mA,, V _O >5V
Under Voltage Lockout Threshold	V _{UVLO-}	10	-	12.5	V	I _F =10mA,, V _O <5V

Switching Characteristics

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Propagation delay time to output High level	t_{PLH}	50	90	300	ns	$I_F = 7 \text{ to } 16\text{mA}$ $V_{CC} = 15 \text{ to } 30\text{V}$ $C_g = 10\text{nF}$, $R_g = 10\Omega$, $f = 10\text{kHz}$, $T_A = 25^\circ\text{C}$ Duty Cycle=50%,
Propagation delay time to output Low level	t_{PHL}	50	125	300	ns	
Pulse width distortion	$ t_{PHL} - t_{PLH} $	-	-	100	ns	
Propagation Delay Skew*5	t_{PSK}	-	-	150	ns	
Output rise time	t_R	-	50	-	ns	
Output fall time	t_F	-	50	-	ns	
Common Mode Transient Immunity at Logic High*6	CM_H	25	-	-	kV/ μS	$I_F = 10\text{mA}$, $V_{CC} = 30\text{V}$, $T_A = 25^\circ\text{C}$ $V_{CM} = 1500\text{V}$
Common Mode Transient Immunity at Logic Low*7	CM_L	25	-	-	kV/ μS	$I_F = 0\text{mA}$, $V_{CC} = 30\text{V}$, $T_A = 25^\circ\text{C}$ $V_{CM} = 1500\text{V}$

Notes:

*4 Max. pulse width=10 μs , max. duty cycle =1%

*5 Propagation delay skew is defined as the difference between the largest and smallest propagation delay times (i.e. t_{PHL} or t_{PLH}) of multiple samples. Evaluations of these samples are conducted under identical test conditions (supply voltage, input current, temperature, etc).

*6 Common mode transient immunity at output high is the maximum tolerable negative dv/dt on the trailing edge of the common mode impulse signal, V_{CM} , to assure that the output will remain high (i.e. $V_O > 15.0\text{V}$)

*7 Common mode transient immunity at output low is the maximum tolerable positive dv/dt on the leading edge of the common mode pulse signal, V_{CM} , to assure that the output will remain low (i.e. $V_O < 1.0\text{V}$)

Typical Electro-Optical Characteristics Curves

Fig.1 Forward Voltage vs. Ambient Temperature

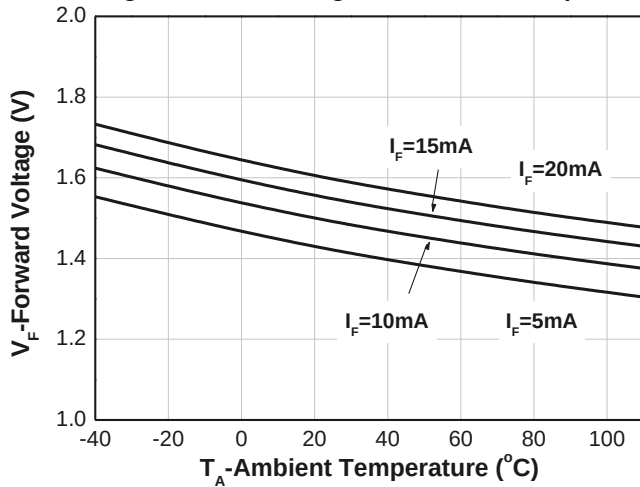


Fig.2 Output High Voltage vs. Output High Current

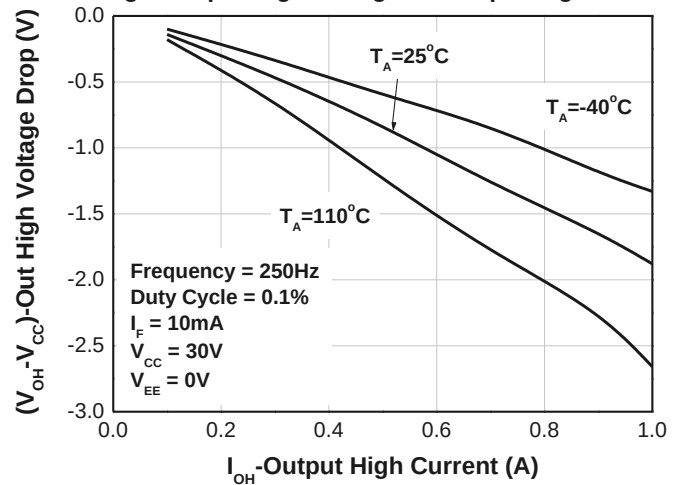


Fig. 3 Output High Voltage Drop vs. Ambient Temperature

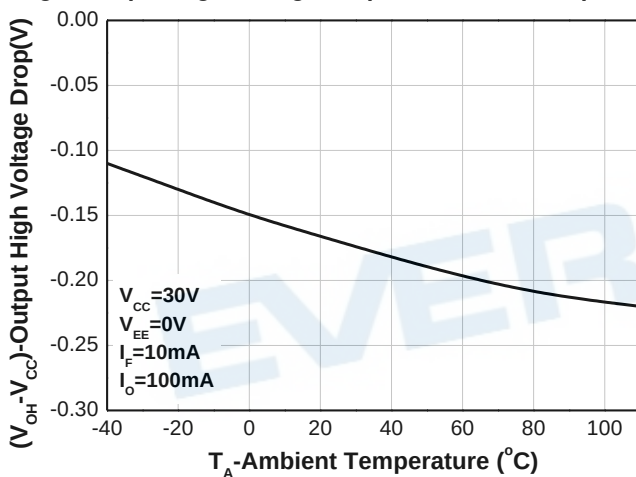


Fig.4 Output Low Voltage vs. Output Low Current

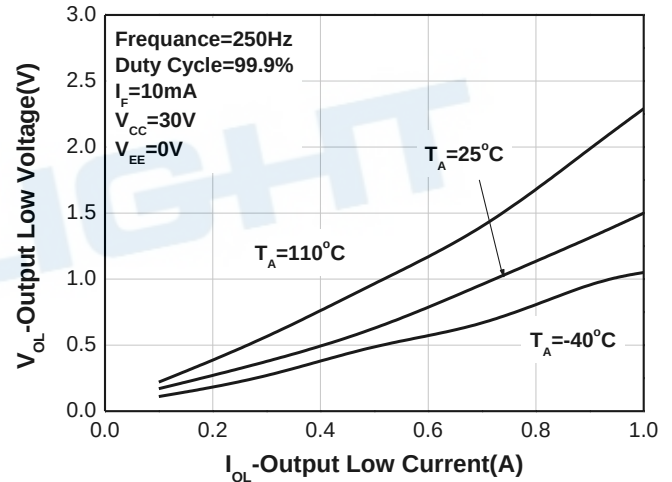


Fig. 5 Output Low Voltage vs. Ambient Temperature

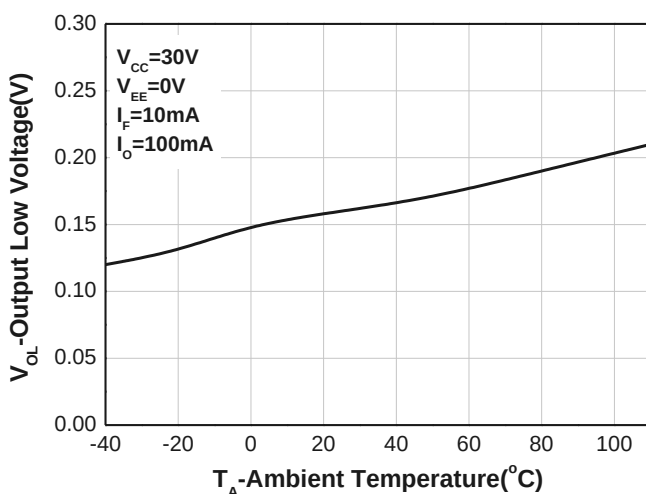


Fig.6 Supply Current vs. Ambient Temperature

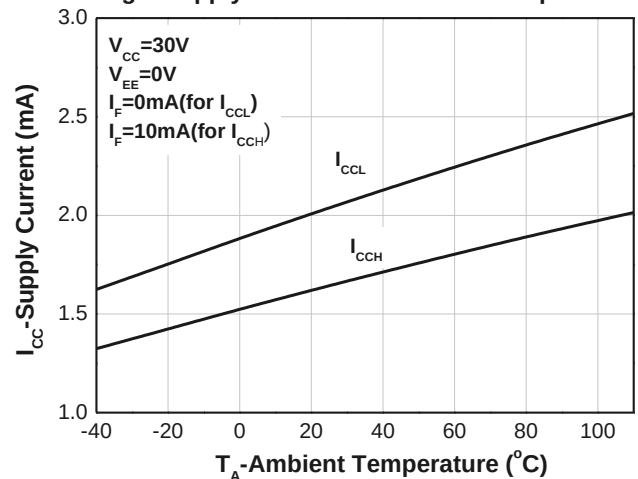


Fig.7 Supply Current vs Supply voltage

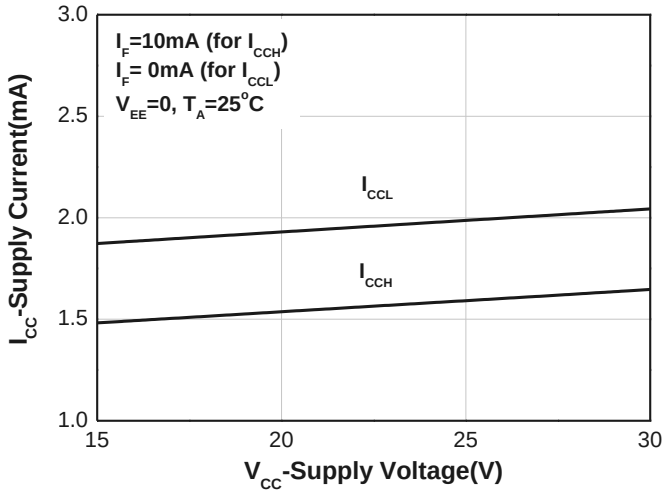


Fig.8 Threshold Input Current vs. Ambient Temperature

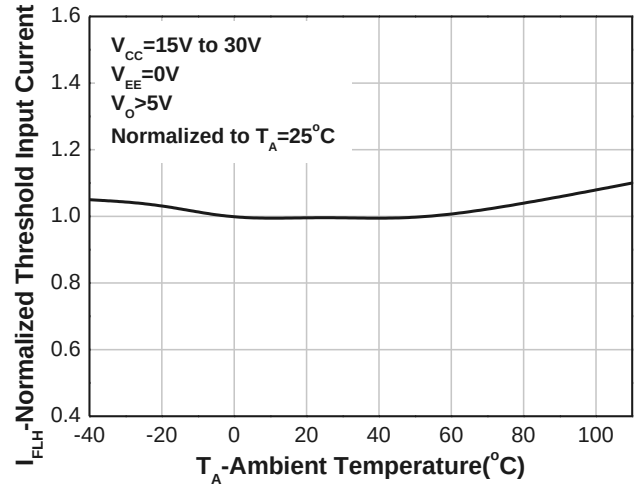


Fig.9. Under Voltage Lockout

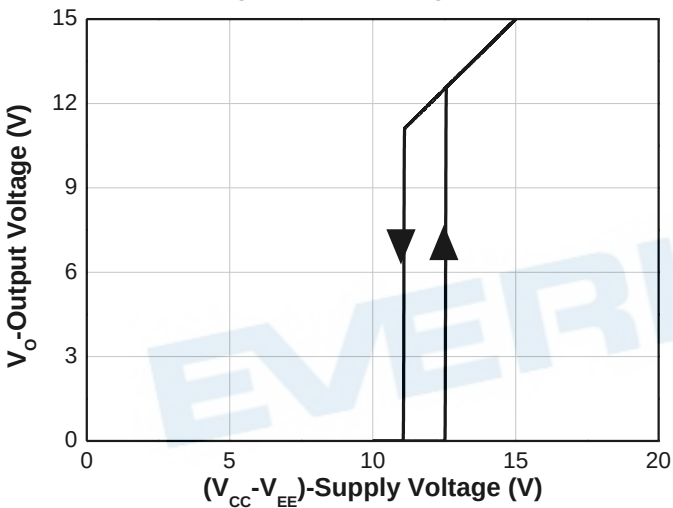


Fig.10 Propagation Delay vs Supply Voltage

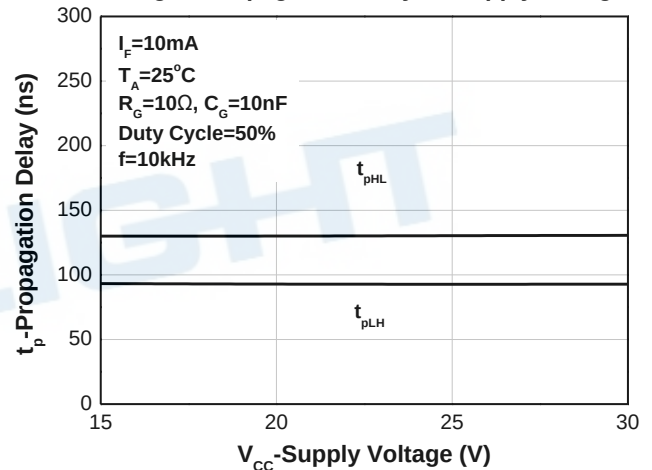


Fig.11 Propagation Delay vs LED Forward Current

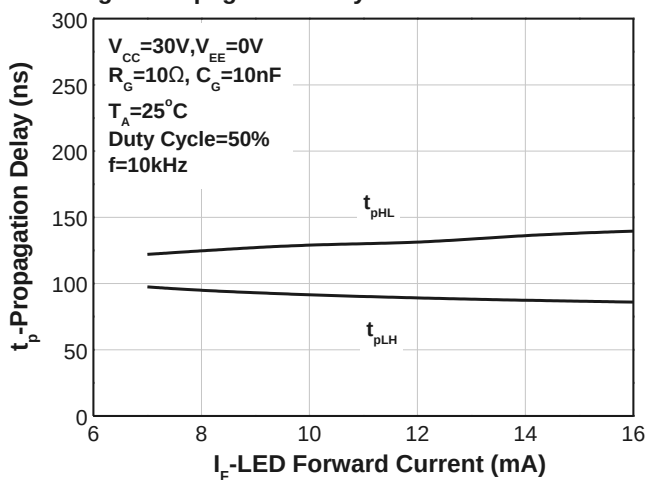


Fig.12 Propagation Delay vs. Ambient Temperature

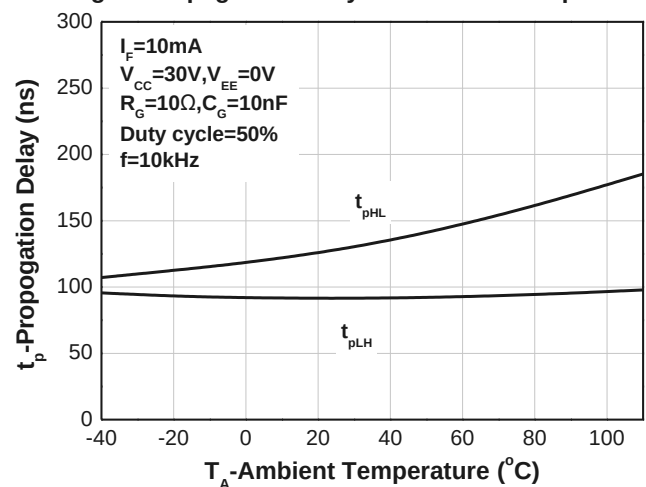


Fig.13 Propagation Delay vs. Serise Load Resistance

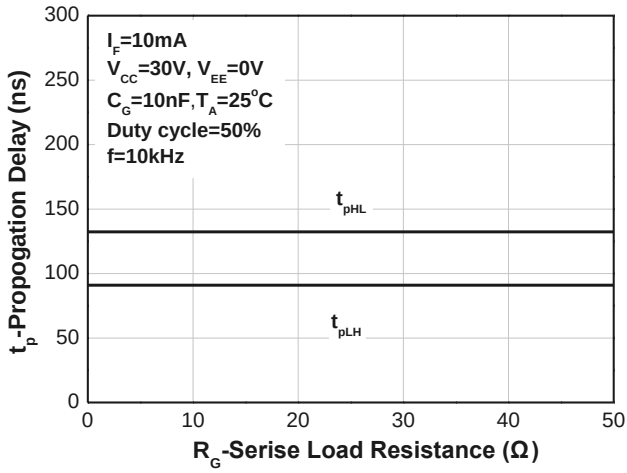


Fig.14 Propagation Delay vs. Load Capacitance

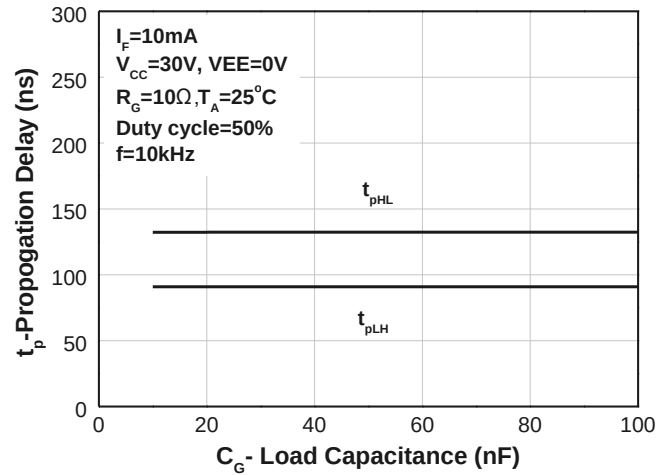


Fig. 15 I_{OH} Test circuit

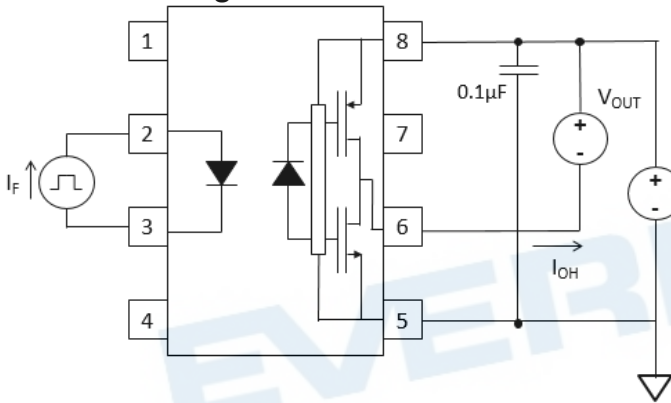


Fig. 16 I_{OL} Test circuit

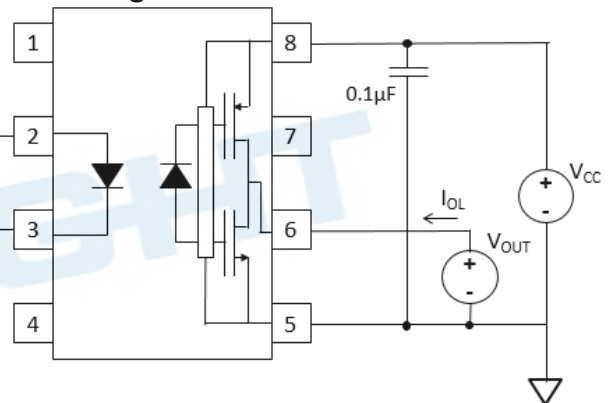


Fig. 17 V_{OH} Test circuit

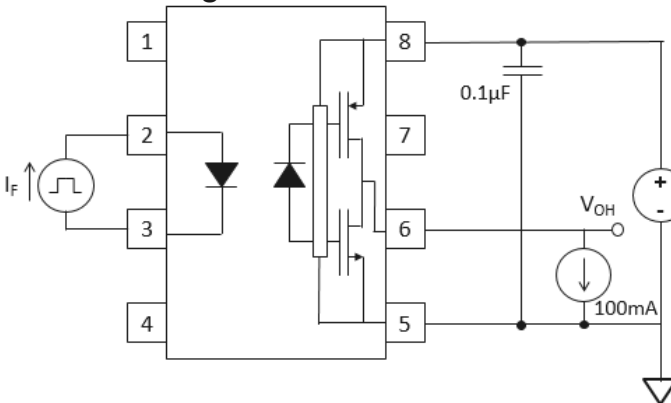


Fig. 18 V_{OL} Test circuit

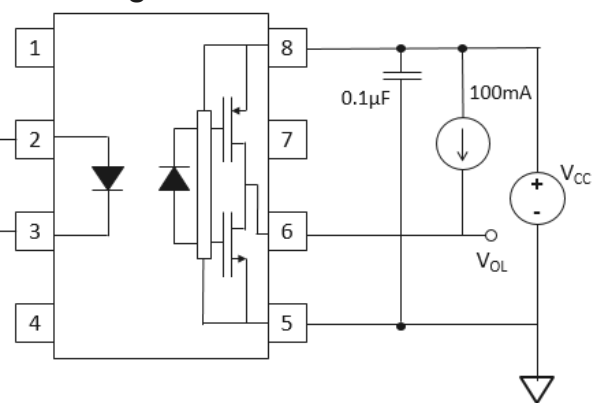


Fig. 19 I_{FHL} Test circuit

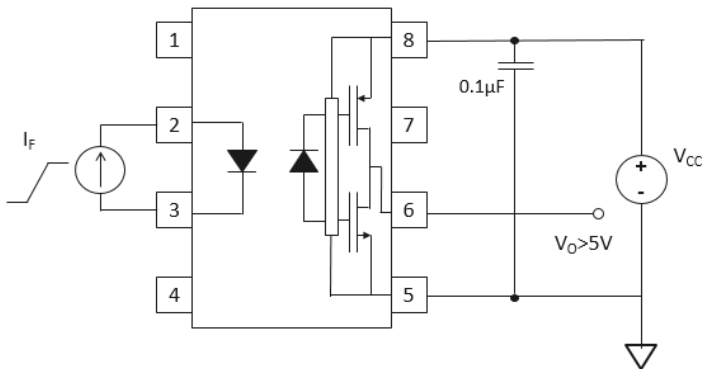


Fig. 20 UVLO Test circuit

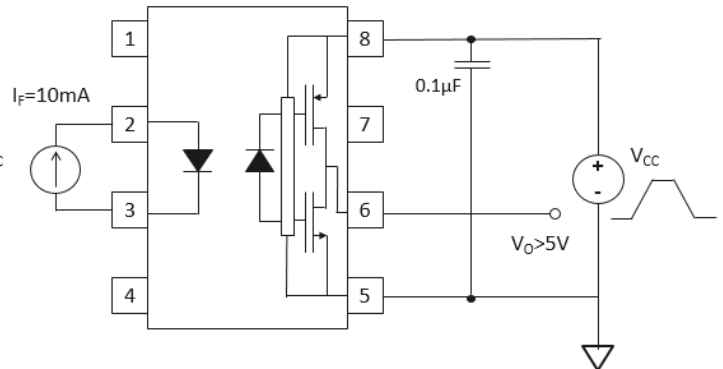


Fig. 21 Switching Time Test circuit

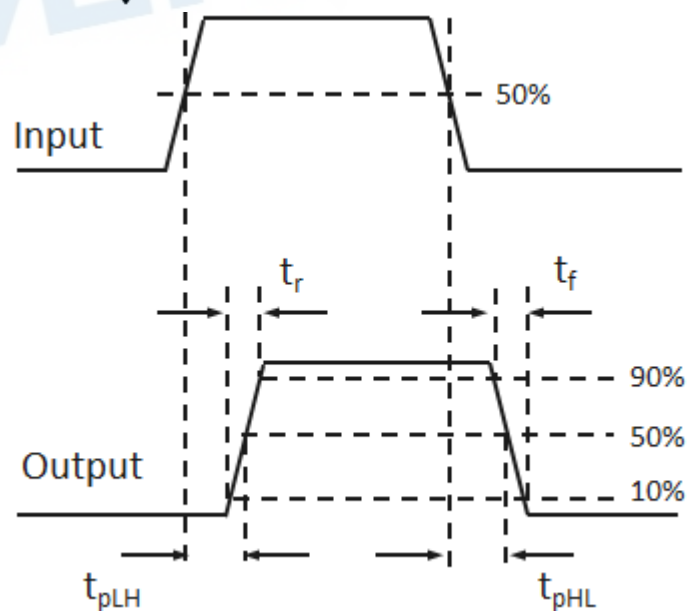
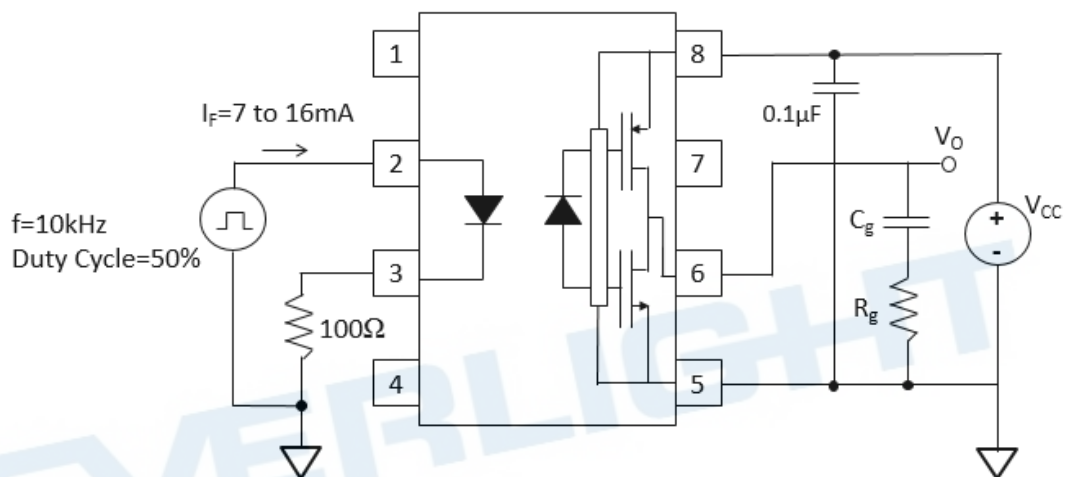
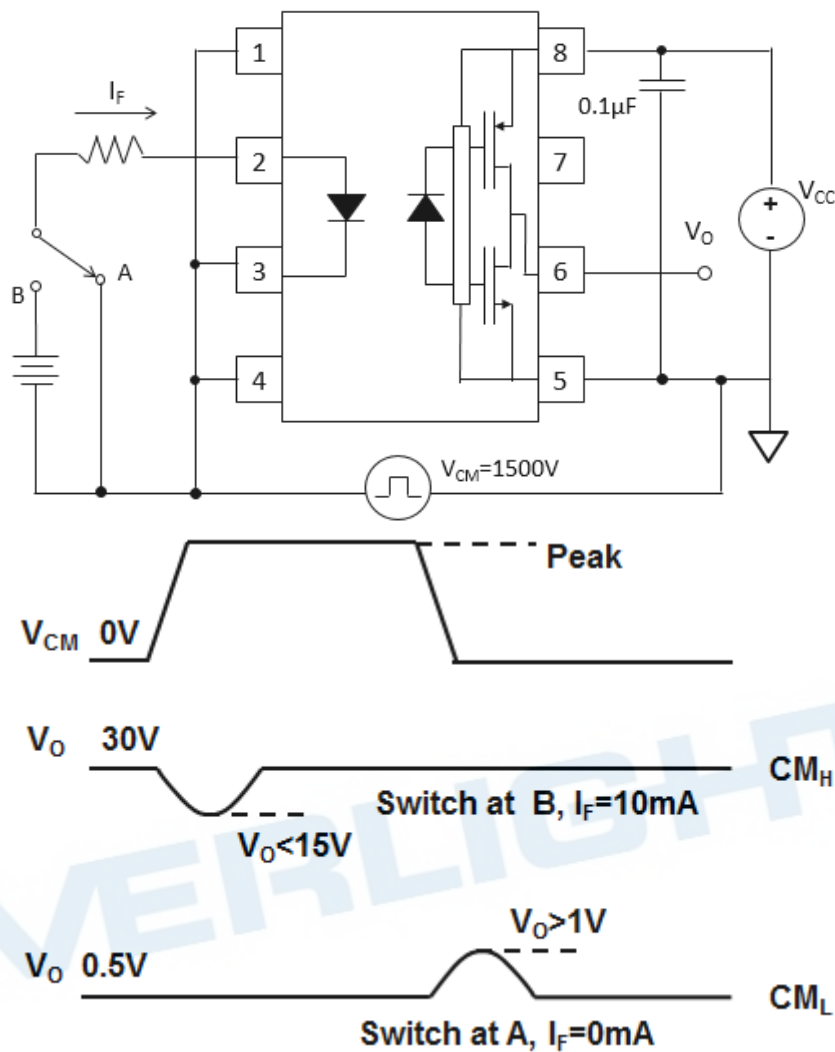


Fig. 22 CMR Test circuit



Order Information

Part Number

EL3150Y(Z)-V

Note

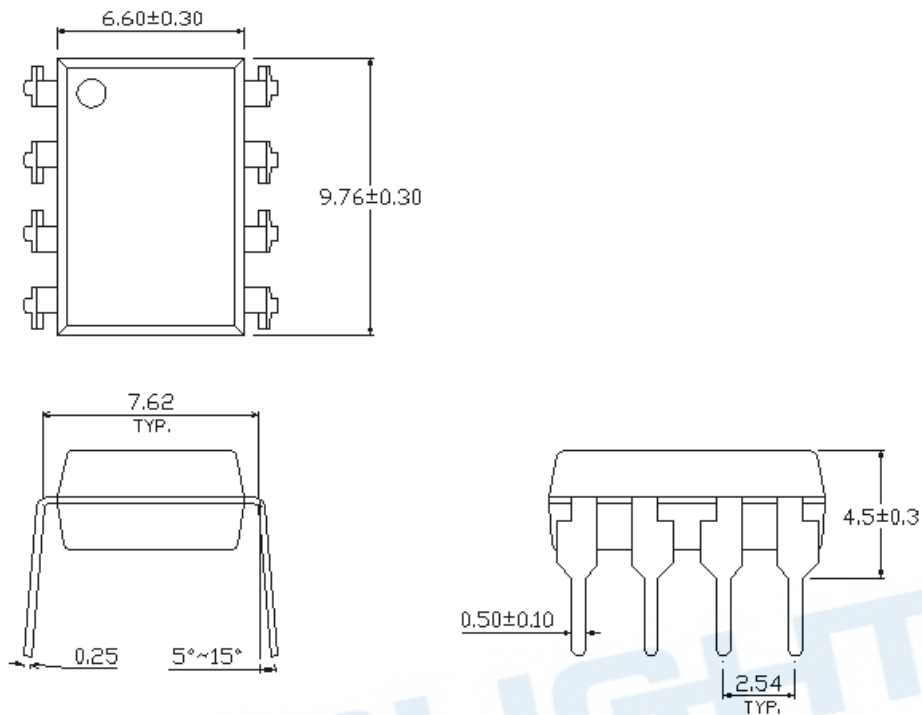
Y = Lead form option (S1 or none)
Z = Tape and reel option (TA, TB or none).
V = VDE safety (optional).

Option	Description	Packing quantity
None	Standard	45 units per tube
(TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
(TB)	Surface mount lead form + TB tape & reel option	1000 units per reel

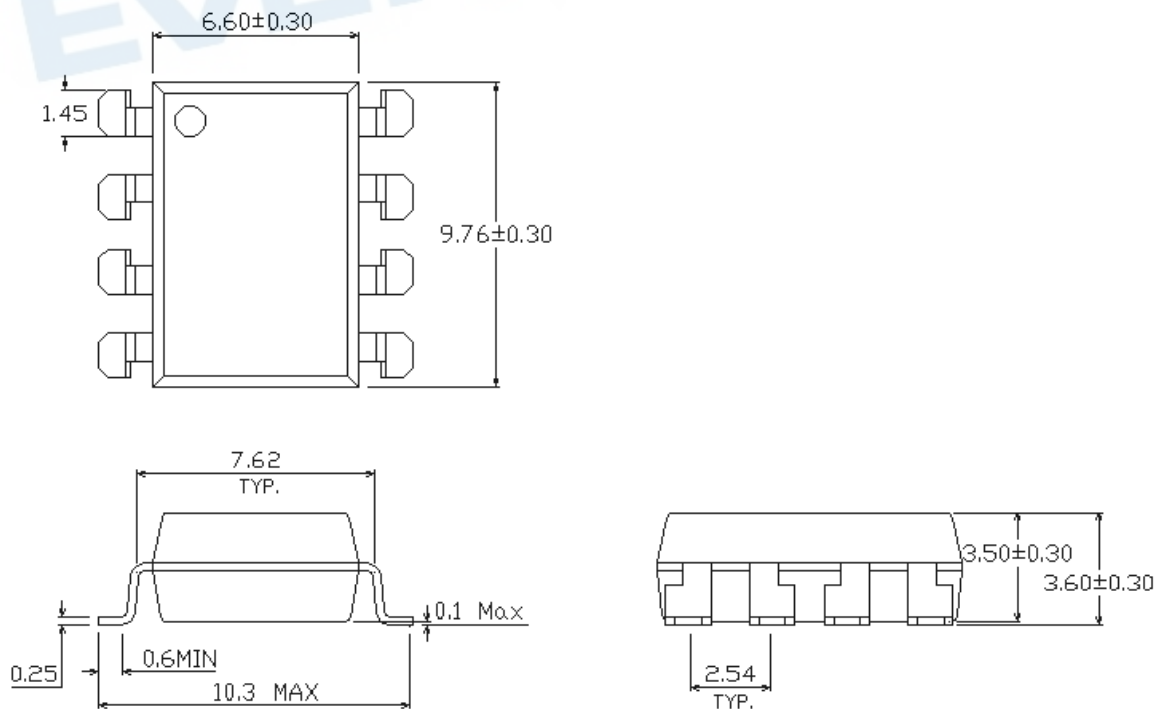
EVERLIGHT

Package Dimension (Dimensions in mm)

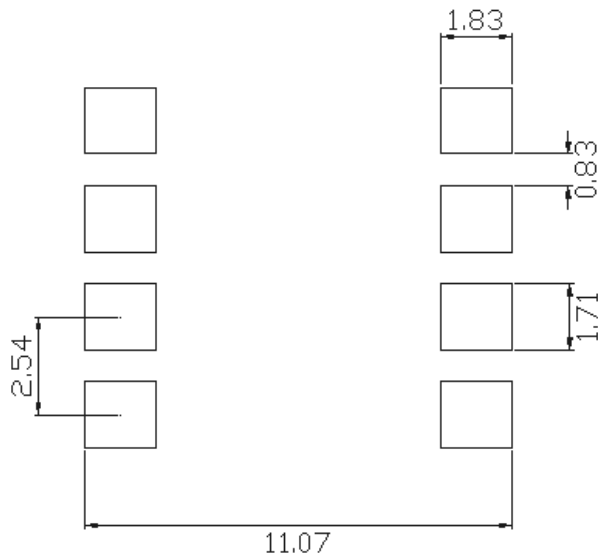
Standard DIP Type



Option S1 Type

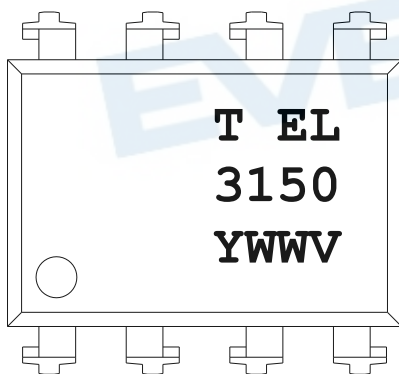


Recommended pad layout for surface mount leadform



Notes.
Suggested pad dimension is just for reference only.
Please modify the pad dimension based on individual need.

Device Marking

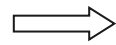
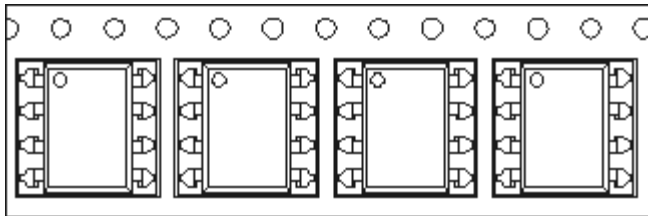


Notes

- | | |
|------|--|
| T | denotes Factory
No code : made in China
T : made in Taiwan |
| EL | denotes EVERLIGHT |
| 3150 | denotes Device Number |
| Y | denotes 1 digit Year code |
| WW | denotes 2 digit Week code |
| V | denotes VDE (optional) |

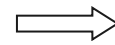
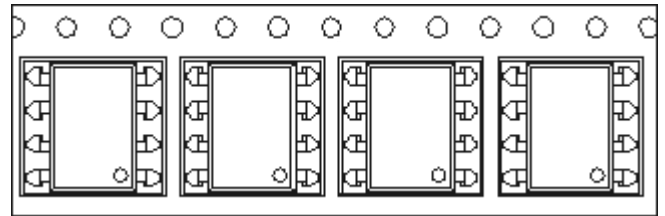
Tape & Reel Packing Specifications

Option TA



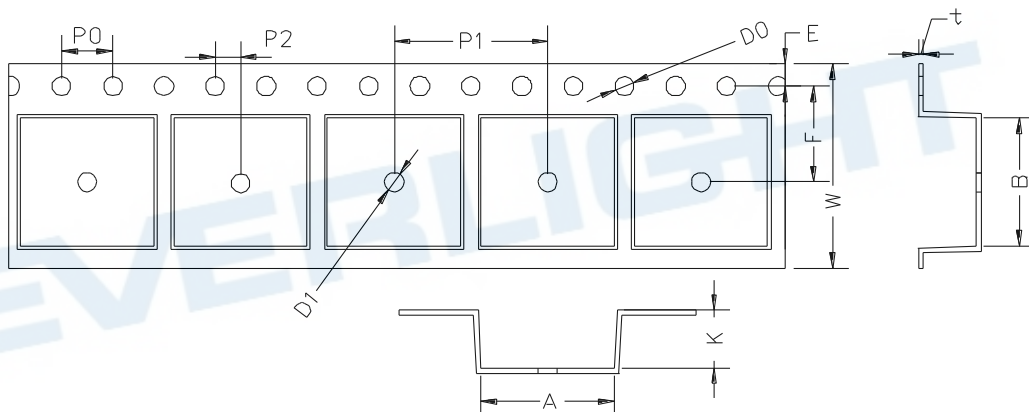
Direction of feed from reel

Option TB



Direction of feed from reel

Tape dimensions

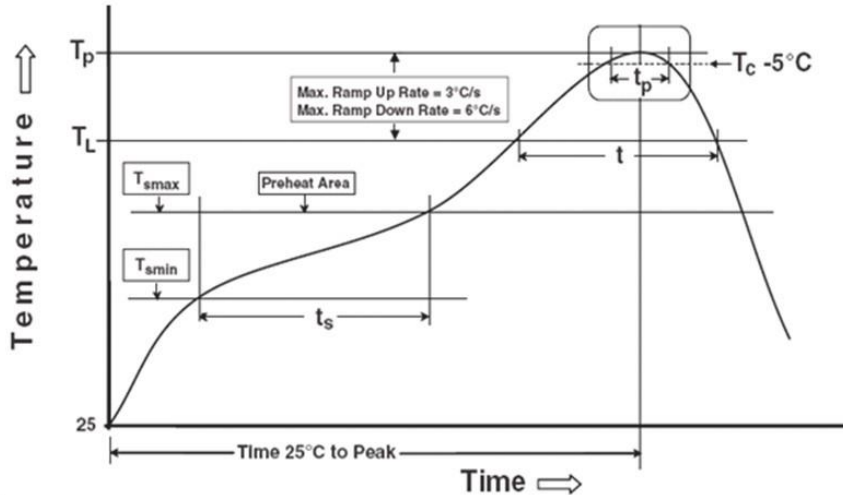


Dimension No.	A	B	D0	D1	E	F
Dimension (mm) S1	10.4±0.1	10.0±0.1	1.5±0.1	1.5±0.25	1.75±0.1	7.5±0.1
Dimension No.	P0	P1	P2	t	W	K
Dimension (mm) S1	4.0±0.1	12.0±0.1	2.0±0.1	0.4±0.1	16.0±0.3	4.5±0.1

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin})	150 °C
Temperature max (T_{smax})	200°C
Time (T_{smin} to T_{smax}) (t_s)	60-120 seconds
Average ramp-up rate (T_{smax} to T_p)	3 °C/second max

Other

Liquidus Temperature (T_L)	217 °C
Time above Liquidus Temperature (t_L)	60-100 sec
Peak Temperature (T_p)	260°C
Time within 5 °C of Actual Peak Temperature: $T_p - 5^\circ\text{C}$	30 s
Ramp- Down Rate from Peak Temperature	6°C /second max.
Time 25°C to peak temperature	8 minutes max.
Reflow times	3 times

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1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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